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Solution growth of a binary icosahedral quasicrystal of Sc₁₂Zn₈₈

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We report the discovery of a binary icosahedral phase in a Sc-Zn alloy obtained through solution-growth, producing millimeter-sized, facetted, single grain quasicrystals that exhibit different growth morphologies, pentagonal dodecahedra, and rhombic triacontahedra, under only marginally different growth conditions. These two morphologies manifest different degrees of quasicrystalline order. The discovery of *i*-Sc₁₂Zn₈₈ suggests that a re-examination of binary phase diagrams at compositions close to crystalline approximant structures may reveal other binary quasicrystalline phases.

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Icosahedral quasicrystals (QCs) discovered 25 years ago¹ possess long-range positional and orientational order but lack the periodic translational order of crystalline solids.² Although they form, almost readily, in a wide variety of ternary and quaternary metallic alloys, examples of stable binary icosahedral quasicrystals are quite rare. Indeed, it has been nearly a decade since the discovery of the only known stable binary icosahedral phases in Cd-Yb and Cd-Ca.^{3,4} Binary alloys offer several important advantages, not the least of which is their simplicity, relative to ternary and quaternary compositions, for structural studies and theoretical treatments.

The Sc-Zn system has been associated with quasicrystal formation for some time.⁵ An icosahedral phase has been identified in Sc₁₅Mg₅Zn₈₀ (Ref. 6) and a large number of ternary and quaternary compositions of the type Sc-*M*-Zn (M=Mn, Fe, Co, Ni, Cu, Pd, Pt, Au, and Ag). In addition, the binary crystalline alloy ScZn₆ (formerly identified as Sc₃Zn₁₇)⁷ has been identified as an approximant of the icosahedral phase. Despite all of this study, the binary "parent" icosahedral phase in the Sc-Zn system has eluded detection. It was then startling when, as part of the exploration of the Sc-Zn binary phase diagram,⁸ we discovered millimetersized facetted grains, with icosahedral morphologies, in flux-grown samples.

Single grains of *i*-Sc₁₂Zn₈₈ quasicrystals were produced using traditional solution-growth methods.9,10 Starting compositions, ranging from Sc_4Zn_{96} to Sc_2Zn_{98} , were heated to 950 °C, cooled to 800 °C over several hours, and then slowly cooled to 480 °C over 30-70 h. At this temperature, the crucibles were removed from the furnace and the remaining liquid decanted. Initial growths were performed using two 2 ml alumina crucibles, one inverted over the other, with silica wool acting as a filtering media during decanting.⁹ Given the substantial vapor pressure of Zn, later growths utilized specially designed threaded alumina crucibles with a threaded alumina straining layer, similar in function to the Ta crucibles described in Ref. 10. For all growths, high-purity Sc and Zn were placed in the lower crucible, and both crucibles were sealed in a silica tube back filled with approximately 0.25 atm of high-purity Ar. Upon opening the crucibles, small facetted grains (Fig. 1) in the shape of either a pentagonal dodecahedron (PD) or rhombic triacontahedron (RT) were found either on the surfaces of crystals of the cubic $ScZn_6$ phase, on the strainer surface or on the walls of the crucible itself.

The PD facetted grains were most commonly grown from initial compositions of Sc_4Zn_{96} and Sc_3Zn_{97} and found in the presence of well-formed and faceted cubic $ScZn_6$. The RT facetted grains were more commonly grown from initial compositions of Sc_2Zn_{98} and also found in the presence of $ScZn_6$; but, due to the reduced Sc content of the initial melt, less of the cubic phase was in evidence. If the growths were cooled to temperatures lower than 480 °C, then platelike crystals of the tetragonal $ScZn_{12}$ phase¹¹ also formed.

Wavelength dispersive x-ray spectroscopy was used to establish the stoichiometry of the PD and RT grains and to rule out the possibility of a third element impurity, leading to a ternary phase. The composition of both the PD and RT grains was found to be a Sc-Zn binary with $12\pm0.3\%$ -atomic Sc and no detectable third elements. Differential scanning calorimetry (DSC) was employed to determine the decomposition temperature of this phase (505 °C) by heating samples of isolated pentagonal grains, as well as masses of RT grains (see inset to Fig. 2). Taken together, these measurements provided a basis for the revised binary phase diagram in the zinc-rich region presented in Fig. 2.¹² A full re-evaluation of the phase diagram, as well as possible rate and nucleation dependencies of the QC phase, is in order, and ongoing.

The structural characterization of the icosahedral phase was accomplished through conventional x-ray powderdiffraction measurements and single grain high-energy x-ray diffraction shown in Fig. 3. Turning first to the growths that produce PD facets, several grains were crushed and prepared for the powder-diffraction measurement. All diffraction peaks could be indexed, using the Elser scheme,¹³ by a primitive (*P*-type) icosahedral phase pattern according to the icosahedral group *m*35. Using the strongest peak along the fivefold axis [labeled 211111 in Fig. 3(a)], the quasilattice constant is a_R =5.017(3) Å.

Both i-Sc₁₂Zn₈₈ (ScZn_{7.3}) and i-YbCd_{5.7} are close in composition to the 1/1 crystalline approximants ScZn₆ (Ref. 7)

PHYSICAL REVIEW B 81, 020201(R) (2010)



FIG. 1. (Color online) Growth morphologies of solution-grown i-Sc₁₂Zn₈₈. Panel (a) shows an example of the PD. Panel (b) shows a cluster of facetted grains displaying a RT morphology. The inset shows an isolated RT grain.

and YbCd₆,¹⁴ although the icosahedral alloy compositions are found on different (e.g., Zn-rich and Zn-poor) sides of the 1:6 composition of their respective approximants.^{12,15} Approximants¹⁶ are large unit-cell periodic structures closely related to QCs in that they share the same basic atomic motifs, or clusters, arranged periodically in the approximant (e.g., as a body-centered cubic packing in ScZn₆ and YbCd₆). Indeed, crystalline approximants have been used to great advantage for investigations of the structural and electronic properties of their quasicrystalline counterparts.^{17–19} We can compare our measured value for a_R to the lattice constant expected for a 1/1 cubic approximant phase through the relation: $a_{q/p} = \frac{2a_R(p+q\tau)}{\sqrt{(2+\tau)}}$, where $\frac{q}{p}$ denotes the order of the approximant (1/1 in this case) and τ is the golden mean $(\frac{\sqrt{5}+1}{2})$. We find a calculated value of $a_{1/1}$ =13.811(8) Å. The lattice parameter for ScZn₆ (space group *Im3*) is reported as



FIG. 2. (Color online) Revised Sc-Zn phase diagram of reference. The Sc-Zn binary phase diagram taken from Ref. 12 is modified to include the quasicrystalline phase (labeled \mathbf{Q}). The inset presents the DSC data on the thermal decomposition of the quasicrystalline phase at 505 °C.

 $a_{1/1}=13.8311(5)$ Å.⁷ This close agreement argues that ScZn₆ will provide a good starting point for the structural refinement of i-Sc₁₂Zn₈₈. Moreover, we note that ScZn₆ is isostructural with YbCd₆, so that both i-Sc₁₂Zn₈₈ and i-YbCd_{5.7} may be described by similar atomic decoration schemes,²⁰ even though there are significant differences between the $\frac{Sc}{Zn}$ and $\frac{Yb}{Cd}$ ratios. Within the context of a Hume-Rothery mechanism for the stabilization of the quasicrystals,² i-Sc₁₂Zn₈₈ yields an e/a (electrons/atom) ratio of 2.12, well within the range of 2.01–2.16 reported for Sc-M-Zn icosahedral alloys and 2.00 for i-YbCd_{5.7}.²¹

In Figs. 3(c) and 3(e), we show the results of high-energy x-ray diffraction measurements taken on station 6ID-D in the MUCAT Sector at the Advanced Photon Source with the incident beam along the fivefold [Fig. 3(c)] and twofold [Fig. 3(e)] axes of a single PD facetted grain. These data were taken using an incident x-ray energy of 129 keV and recorded on a MAR 345 area detector. The use of high-energy x-rays ensures that the structure of the sample bulk (rather than surface) is probed and, by rocking the sample through small angular ranges about axes perpendicular to the beam, provides an image of reciprocal space planes that lie normal to the beam direction.²² All diffraction spots in the twofold and fivefold planes can be indexed to the icosahedral phase and lie, within the resolution of the detector, at the predicted positions. Note that as one moves from the center to the periphery of the pattern, diffraction spots from higher-order zones are also in evidence. For instance, the weak peak in the center of pentagon B in Fig. 3(c) is not observed in neighboring pentagon A since it does not originate in the fivefold plane but slightly above it (within the range over which the sample is rocked). Close inspection of the sequence of diffraction peaks along the fivefold axis in Fig. 3(c) does not reveal any peaks at positions expected for a face-centered icosahedral quasilattice, confirming that the structure is P-type icosahedral. Furthermore, the high-energy x-ray diffraction patterns establish that the full 0.5 mm³ volume of the sample shares the same orientation, so that the grain is properly characterized as a "single quasicrystal."

The fact that the PD grains are bulk quasicrystals taken together with the method of growth provides strong evidence that $i-Sc_{12}Zn_{88}$ is a stable phase. The quasicrystal forms during a 30–70 h cooling process to 480 °C followed by cooling to room temperature over approximately 10 min. We have also annealed as-grown samples at 390 °C for 22 h in one atmosphere of Ar and found neither morphological nor structural changes as evidenced by visual inspection, the x-ray Laue pattern, and x-ray powder diffraction. If $i-Sc_{12}Zn_{88}$ is not thermodynamically stable at room temperature, it is quite robust to the temperature-time treatment described above to the degree of remaining a bulk single grain quasicrystal, as evidenced by Figs. 2 and 3.

For the RT facetted grains, Figs. 3(b), 3(d), and 3(f) show the powder and single grain x-ray diffraction measurements analogous to those for the PD sample. The powderdiffraction profile for the RT sample is shown Fig. 3(b) and yields the same value for a_R , as the PD sample. A comparison between features observed in the single grain highenergy x-ray diffraction measurements, however, show some interesting differences. A distinct smearing of the diffraction

PHYSICAL REVIEW B 81, 020201(R) (2010)



FIG. 3. (Color online) Powder diffraction and high-energy x-ray diffraction from single grains of i-Sc₁₂Zn₈₈. Powder-diffraction pattern from powders of the PD facetted grains and RT facetted grains are shown in panels (a) and (b), respectively. Icosahedral indices using Elser's notation (Ref. 13) are shown. Single grain high-energy x-ray diffraction patterns measured along the fivefold axis and twofold axes are shown in panels (c) and (e) for the PD grain and (d) and (f) for the RT sample. The lines in panel (e) indicate the twofold, threefold, and fivefold directions in the twofold scattering plane. The weak peak in the center of pentagon B in panel (c) is not observed in neighboring pentagon A since it does not originate in the fivefold plane, but slightly above it (within the range over which the sample is rocked).

peaks (on the order of 1°) in the transverse direction was observed for all of the RT grains investigated and the longitudinal (radial) diffraction peak widths are approximately a factor of 2 broader than those of the PD grains. The peak positions remain well indexed by the icosahedral phase but the peak broadening points to a lower degree of "quasicrystallinity" in the RT grains, relative to the PD grains. The finite mosaic of these samples may arise from misorientations between different regions of the grain that may be related to the growth conditions for the RT grains.

i-Sc₁₂Zn₈₈ offers opportunities for investigations of the structure, formation, growth, and stability of aperiodic alloys. For example, this binary icosahedral phase exhibits different growth morphologies under only marginally different growth conditions, and we have found that the degree of quasicrystalline order differs between the PD and RT grains. Together with the ternary Sc-*M*-Zn icosahedral alloys, *i*-Sc₁₂Zn₈₈ offers an avenue for systematic investigations of the effects of chemical substitution as well as formation and growth conditions on quasicrystalline order. Furthermore, the x-ray cross sections for Sc (Z=21) and Zn (Z=30) provide reasonable contrast for structural measurements, but, relative to *i*-YbCd_{5.7}, *i*-Sc₁₂Zn₈₈ also offers the advantage of allowing both neutron-diffraction and inelastic-scattering measure-

ments on samples without the need for isotopic substitution (Cd is highly neutron absorbing).

Finally, it is worth noting that the proposed region of exposed liquidus line for primary solidification of the $i-Sc_{12}Zn_{88}$ icosahedral phase is very limited (Fig. 2). It is not surprising, then, that this phase eluded discovery for so long, despite recent studies of related binary approximant phases. This said, the obvious and tantalizing question is how many other quasicrystalline phases have been missed (or are yet to be found) in the proximity of binary approximants? Solution growth experiments that sample the cascading peritectics associated with binary liquidus lines may lead to as yet undiscovered binary quasicrystalline alloys.

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